

**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

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First Named Inventor	Ryouichi TAKEUCHI
Art Unit	2811
Examiner Name	Vernon P. WEBB
Attorney Docket Number	Q80875

**U.S. PATENTS**

Examiner Initials*	Cite No	Patent Number	Kind Code <sup>1</sup>	Issue Date	Name of Patentee or Applicant of cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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**U.S. PATENT APPLICATION PUBLICATIONS**

Examiner Initials*	Cite No	Publication Number	Kind Code <sup>1</sup>	Publication Date	Name of Patentee or Applicant of cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
/V.W./	1	20030141509	A1	2003-07-31	UDAGAWA	

**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Cite No	Foreign Document Number <sup>3</sup>	Country Code <sup>2</sup>	Kind Code <sup>4</sup>	Publication Date	Name of Patentee or Applicant of cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>5</sup>
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**NON-PATENT LITERATURE DOCUMENTS**

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/V.W./	1	Y. HOSOKAWA, et al.; "High-power ohmic-electrodes dispersive AlGaNp double-hetero structure yellowish-green light-emitting diodes"; Journal of Crystal Growth 221 (2000); pp. 652-656	

**EXAMINER SIGNATURE**

Examiner Signature	/Vernon Webb/	Date Considered	12/06/2008
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through a citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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3. For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 4. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. 5. Applicant is to place a check mark here if English language translation is attached.